

isc N-Channel MOSFET Transistor

PSMN3R4-30PL

FEATURES

- Drain Current –I_D= 100A@ T_C=25 $^\circ\!\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}= 30V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 3.4m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

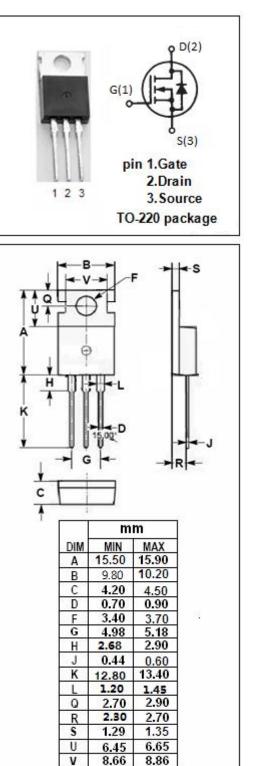
• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25 C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	30	V			
V _{GS}	Gate-Source Voltage-Continuous	±20	V			
ID	Drain Current-Continuous	100	A			
I _{DM}	Drain Current-Single Pluse	609	А			
P _D	Total Dissipation @Tc=25℃	114	w			
TJ	Max. Operating Junction Temperature -55~175		°C			
T _{stg}	Storage Temperature	-55~175	°C			

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.0	°C/W



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¹ *isc & iscsemi* is registered trademark



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	30		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 1mA	1.3	2.15	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 10A		3.4	mΩ
lgss	Gate-Body Leakage Current	V _{GS} = ±16V;V _{DS} = 0		±100	nA
loss	Zero Gate Voltage Drain Current	V _{DS} = 30V; V _{GS} = 0		5.0	μA
V _{SD}	Forward On-Voltage	I _S = 10A; V _{GS} = 0		1.2	V

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